

isc N-Channel MOSFET Transistor

AOD3N80

• FEATURES

- With TO-252(DPAK) packaging
- High speed switching
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

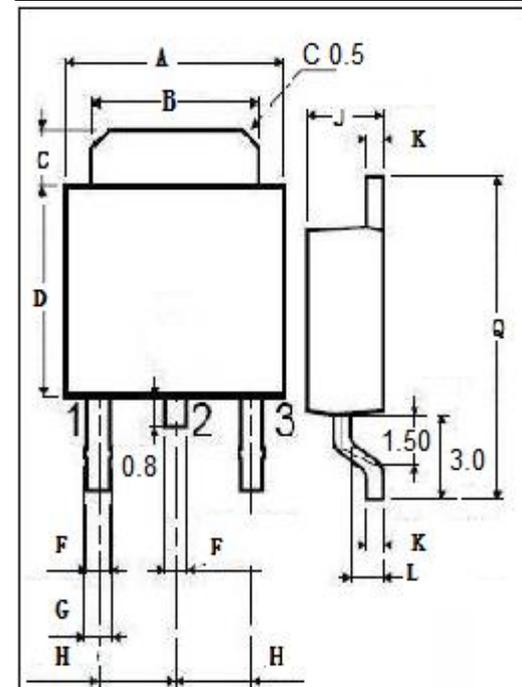
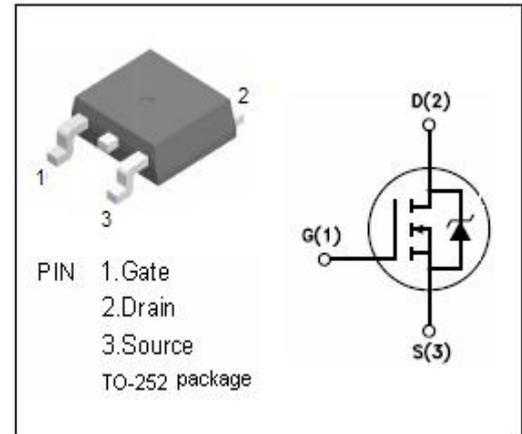
- Power supply
- DC-DC converters
- Motor control
- Switching applications

• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	800	V
V _{GSS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous	2.8 1.8	A
I _{DM}	Drain Current-Single Pulsed	9	A
P _D	Total Dissipation	83	W
T _j	Operating Junction Temperature	-50~150	°C
T _{stg}	Storage Temperature	-50~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(ch-c)}	Channel-to-case thermal resistance	1.5	°C/W
R _{th(ch-a)}	Channel-to-ambient thermal resistance	55	°C/W



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1

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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	800			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =5V; I _D =0.25mA	3.3		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =1.5A		3.8	4.8	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V; V _{DS} = 0V			±0.1	μ A
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 800V; V _{GS} = 0V; T _J =25°C V _{DS} = 640V; V _{GS} = 0V; T _J =125°C			1 10	μ A
V _{SDF}	Diode forward voltage	I _{SD} =1A, V _{GS} = 0 V			1.0	V

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